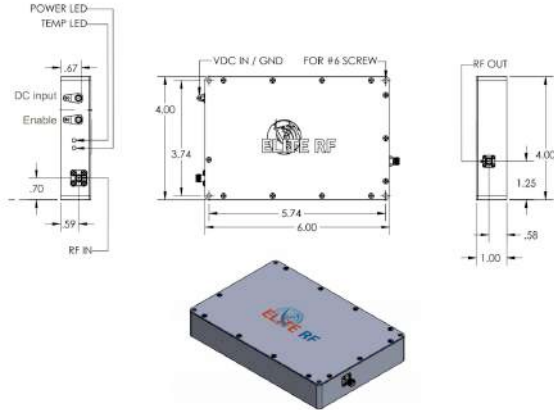


General Description:

This power amplifier designed for CW/Digital/Pulse signals and general-purpose amplification. Using advanced high power density LDMOS and GaN semiconductor devices, these high-performance amplifiers achieve high efficiency, high gain, and wide dynamic range. Like all Elite RF amplifiers, the product comes with an industry leading **5-year warranty**



Features	Indicator options	Protections
12.0 GHz	DC Power	Thermal Overload
32 watts	Temp Fault	Over Voltage
40 dB gain		Reverse Polarity
Class AB		
20 VDC		
On/Off Enable- Ground to disable amplifier		

ELECTRICAL SPECIFICATIONS

Parameter	Symbol	Min	Typ	Max	Unit
Frequency Range	BW	12.0		12.0	GHz
Output Power CW	Psat		32		Watt
Output Power at 1 dB Compression	P1dB		-		Watt
Small Signal Gain	Gp		44		dB
Gain Flatness @ Psat	Delta Gp 1		+/- 1		dB
Input VSWR	S11		2:1		-
IMD	IP3		-		dBm
Harmonics at 32 Watts	H		-15		dBc
Spurious Signals	Spur		-60		dBc
Operating Voltage	VDC	19	20	21	VDC
Current at 32 watts	Current		5		Amps
Class of Operation	C		AB		Class
Noise Figure	NF		5		dB
Large Signal Gain @ 20 watts	Lsg		40		dB

ENVIRONMENTAL CHARACTERISTICS

Parameter	Symbol	Min	Typ	Max	Unit
Operating Case Temperature	Tc	-20		+60	Deg C
Storage Temperature	Tstg	-40		+85	Deg C
Relative Humidity (non-condensing)	RH			95	%
Altitude	ALT			10,000	Feet
Vibration/Shock	VI /SH			Normal Truck Transport	

MECHANICAL CHARACTERISTICS

Parameter	Symbol	Min	Typ	Max	Unit
Dimensions	Dim		6.0 x 4.0 x 1.0		Inches
Weight	Wt.		1.5		lbs.
Connectors In/Out	RF Conn		SMA/2.92 mm		-
Cooling	Th		Heatsink required		-